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UV Absorption in metal decorated Boron nitride flakes: A theoretical analysis of excited states

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Abstract

The excited states of single metal atom ($X = \text{Co}, \text{Al}$ and Cu) doped boron nitride flake (MBNF) $\text{B}_{15}\text{N}_{14}\text{H}_{14}\text{-X}$ and pristine boron nitride ($\text{B}_{15}\text{N}_{15}\text{H}_{14}$) are studied by time-dependent density functional theory. The immediate effect of metal doping is a red shift of the onset of absorption from about 220 nm for pristine BNF to above 300 nm for all metal doped variants with the biggest effect for MBNF-Co, which shows appreciable intensity even above 400 nm. These energy shifts are analyzed by detailed wavefunction analysis protocols using visualization methods, such as the natural transition orbital analysis and electron-hole correlation plots, as well as quantitative analysis of the exciton size and electron-hole populations. The analysis shows that the Co and Cu atoms provide strong contributions to the relevant states whereas the aluminum atom is only involved to a lesser extent.

Keywords: boron-nitride; TDDFT; excited state analysis; NTO; charge transfer

1. Introduction

Boron nitride materials are an active area of research due to their unique properties like high hardness and excellent chemical and thermal stabilities, which make them suitable in many potential applications like hydrogen and carbon dioxide storage media, sensing applications, piezoelectric and nanoelectronic devices¹⁻⁵. Noticeably, there have been a few studies devoted to the optical properties of boron nitride nanoribbons (BNNRs) and nanotubes (BNNTs)^{6,7}. It has been experimentally shown that boron nitride nanosheets can be used as deep-UV photodetectors⁸. Carbon doping has been tested to tune the optical response of boron nitride nanodots⁹. Recently, boron nitride structures have been investigated for the purpose of hydrogen storage¹⁰, where the addition of metal nanoparticles like platinum was found to boost the hydrogen storage capacity¹¹. It is also known that the pure boron nitride systems do not bind hydrogen

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substantially¹². There are reports^{13,14} on the study of electronic and magnetic properties of single transition metal atom doped BNNRs which demonstrate their potential applications in spintronics and magnetic data storage. In our recent report¹⁵, we have implemented the density functional theory (DFT) and time-dependent density functional theory (TDDFT) based calculations for the study of ground state properties and photo-absorption of boron nitride flakes (BNFs) both in pure and single metal atom doped forms, replacing a nitrogen atom by the metal. The metal atoms used were Ni⁺, Fe⁺, Co, Cr⁺, Cu and Al. It was reported that the electronic gap of pure BNF shifts from insulating to semiconducting nature on single metal atom doping, along with the red shift in the absorption wavelengths from ultraviolet to visible region. So far, no experimental reference data on these systems are available. Following Ref. 15, the same systems are studied here but enhanced insight into the electronic wavefunctions involved is provided through extended analysis tools.

Time-dependent linear response density functional theory (TDDFT) has been commonly used to describe the electronic excitations of molecular many-particle systems¹⁶⁻¹⁹. In the TDDFT framework, electronic excitation energies and oscillator strengths of molecular systems are easily calculated. However, the more intricate details of the resulting response functions are often ignored or analyzed only superficially in the discussions. An analysis of excited states is particularly challenging in the case of extended molecular systems, as two contradicting viewpoints come into play for these systems²⁰⁻²²: the molecular orbital (MO) and exciton quasiparticle representations. The former is needed to understand molecular details and to visualize the general state character ($\pi\pi^*$, $n\pi^*$ etc.) whereas the latter provides more immediate insight into electron-hole correlations in larger systems. Recently, an extensive analysis framework was developed that allows to bridge between these concepts²³⁻²⁶. The central concept of these analysis strategies is a two-body exciton wavefunction, which is constructed from the transition density matrix (1TDM). Starting from this concept, a wide range of visual and quantitative analysis methods can be defined. In the following, we start by applying the popular concept of the natural transition orbital transformation (NTO)^{24,27}. The NTOs generally provide a more compact representation as opposed to the Hartree-Fock orbitals and are a convenient method to visualize the excitation hole and the excited electron. We proceed by computing electron-hole correlation plots^{23,28-30} to provide a more compact description of the different excitation processes. Finally, two quantitative analysis methods are explored: an electron-hole population analysis and the computation of exciton sizes. Application of these methods does not

only provide detailed insight into the excited states of MBNFs but also allows studying the interrelations between the analysis methods. Recently one of the authors has employed similar transition density matrix based analysis to describe the excited states in graphene nanoribbons (GNR), both in pure and metal doped forms³¹. The present study supersedes this previous work by applying a more extended set of analysis methods and by performing a more fine-grained analysis of the electron-hole distributions.

2. Methodology

Structures considered in this study are the boron nitride flakes (BNFs) both in pure ($B_{15}N_{15}H_{14}$) and neutral single-metal-atom doped ($B_{15}N_{14}H_{14}-X$, where $X=Al, Co$, and Cu) forms, from our previous study¹⁵ (**Fig.1**). All the calculations were performed with the Firefly version 8.1.0, build number 8800 program code³². TDDFT results at B3LYP/6-31+G (d,p) level of theory under Tamm-Dancoff approximation, for the single-photon absorption were used. The lowest 100 singlet excited states were studied. Analysis of excited state wavefunctions was performed by means of the TheoDORE software package³³ using the cclib library for data parsing³⁴ and the Jmol package for plotting³⁵.

Fig 1. Metal doped ($B_{15}N_{14}H_{14}-X$) BNF showing the common doping site for all the MBNF; where orange, blue, and grey colored atoms denote boron, nitrogen and hydrogen atoms. The large blue atom denotes the dopant metal atom.

3. Results and Discussion

3.1 Absorption strengths

The computed stick spectra for UV/Vis absorption are presented in **Fig. 2**. This figure reflects the results given in a recent study by one of the authors¹⁵: Metal doping produces a general red shift in the absorption spectrum and a reduction of the oscillator strengths. Both effects are strongest for MBNF-Co. Due to the large number of similar excitations in these systems it is not possible to provide a detailed description of all these states. Therefore, only some representative states are chosen for a more detailed analysis. This is done on the basis of higher oscillator strengths or for covering a higher absorption range. The oscillator strengths f of these states are listed in **Table 1**. Oscillator strengths (f) were determined using Casida equations^{17,18,36}, as implemented in the FIREFLY code.

Fig. 2 Plots of Oscillator strength vs Excitation wavelength for all the BNFs. The arrow marks represent the transitions which are discussed in subsequent sections.

Table 1. Oscillator strengths (f) between the ground and n^{th} excited state of all BNFs, are listed

BNF	State transition	6-31+G (d,p)	
		λ (nm)	f
Pure	$S_0 \rightarrow S_2$	218	0.11
	$S_0 \rightarrow S_{14}$	194	0.37
	$S_0 \rightarrow S_{94}$	159	0.37
MBNF-Al	$S_0 \rightarrow S_{51}$	208	0.08
	$S_0 \rightarrow S_{61}$	201	0.13
	$S_0 \rightarrow S_{77}$	192	0.18
MBNF-Co	$S_0 \rightarrow S_7$	411	0.02
	$S_0 \rightarrow S_9$	399	0.03
	$S_0 \rightarrow S_{69}$	214	0.07
	$S_0 \rightarrow S_{96}$	200	0.03
MBNF-Cu	$S_0 \rightarrow S_1$	511	0.01
	$S_0 \rightarrow S_{17}$	248	0.08
	$S_0 \rightarrow S_{55}$	203	0.10
	$S_0 \rightarrow S_{84}$	187	0.25

3.2 Natural Transition Orbitals (NTOs)

To provide a compact description of the excitation process, the natural transition orbital (NTO) representation is chosen. The NTOs are constructed through a singular value (SV) decomposition^{9,23,27}:

$$\mathbf{D} = \mathbf{U} \text{diag}(\sqrt{\lambda_1}, \sqrt{\lambda_2}, \dots) \mathbf{V}^T$$

Here $\mathbf{D}$ is the transition density matrix, constructed from TDDFT response vector. $\mathbf{U}$ and $\mathbf{V}$ are the unitary matrices describing the hole and particle orbitals. The $\lambda_i (\leq 1)$ values denote the weights of the respective configurations.

Fig. 3 illustrates the NTOs corresponding to the dominant singlet transitions ($S_0 \rightarrow S_n$) of all the structures along with the corresponding weights, λ_i . The singlet excitations are described by single or multiple set of NTOs each (with λ_i), as shown in **Fig. 3**. The extent of electron delocalization in pristine BNF is seen from **Fig. 3**, where the exciton wave function in the hole NTOs is concentrated primarily on the electron-rich nitrogen atoms spreading almost entirely on the BNF, and in the particle NTOs (upon excitation) it gets accumulated on the electron-deficient boron atoms almost entirely. But this picture of electron delocalization changes on doping.

In MBNF-Al, the electron delocalization enhances with electron density moving away from nitrogen (in hole NTOs) and builds up on the boron, aluminium and hydrogen atoms (in particle

Fig. 3 Natural transition orbitals (NTOs) for the dominant excitations of all the BNFs, a) Pure, b) MBNF-Al, c) MBNF-Co and d) MBNF-Cu. The values in brackets represent the weights (λ_i) of respective NTOs. The arrow indicates the location of single metal atom in MBNFs. Pink and blue atoms denote boron and nitrogen atoms.

NTOs) spanning a larger area. In MBNF-Co, the electron cloud is concentrated on or around the cobalt and boron atoms and moves around insignificantly in the particle NTOs ($\lambda_i = 0.88$). Also,

in NTOs with $\lambda_i = 0.67$, the electron density moves from cobalt and nitrogen atoms, towards the boron atoms. Finally, in MBNF-Cu, the exciton wave function is concentrated on and around the copper atom and moves towards the terminal hydrogens and boron atoms on absorption. In our previous report³¹, the electron delocalization in metal doped graphene nanoribbons (GNRs) was found in the ascending order $Al^+ \rightarrow Cu^+ \rightarrow Co^+$.

3.3 Charge transfer numbers and electron-hole correlation plots

The charge transfer numbers (Ω_{AB}) are calculated by summing up 1TDMs corresponding to the contributions from individual atoms/fragments **A** and **B**^{23,37} based on the following equation:

$$\Omega_{AB} = \frac{1}{2} \sum_{\mu \in A} \sum_{\nu \in B} [(DS)_{\mu\nu}(SD)_{\mu\nu} + D_{\mu\nu}(SDS)_{\mu\nu}],$$

where the summations run over the basis functions placed on **A** and **B**, respectively. “**S**” is the overlap matrix between the basis functions. Ω_{AB} corresponds to the simultaneous probability that the hole is on fragment **A** while the electron is on **B** in the exciton picture.²⁴ The weight of local excitations on fragment **A** is given by the diagonal element Ω_{AA} while charge transfer components are represented by off-diagonal elements Ω_{AB} ($A \neq B$). The Ω matrix can be visualized as a pseudocolor matrix plot yielding the so-called electron-hole (e-h) correlation plots. This representation, which is similar to 1TDM-based visualization techniques reported previously,²⁸⁻³⁰ provides a compact representation of excited state localization and charge transfer. In the present study the system was divided into four formal fragments corresponding to the different atom types **M** (metal), **H** (hydrogens), **B** (borons) and **N** (nitrogens). Thus, as shown in the top panel of **Figure 4**, 4x4 matrices are obtained representing the individual local and charge transfer contributions. The local contributions ($M \rightarrow M$, $H \rightarrow H$, $B \rightarrow B$, and $N \rightarrow N$) are located in the main diagonal (going from the lower left to the upper right) while the charge transfer contributions correspond to the off-diagonal elements. The weight of each individual type of excitation is encoded in grey scale.

Figure 4 illustrates the e-h correlation plots for the dominant excitations in the different MBNFs. To start with, in case of pure BNF, all the bright excitations S_2 , S_{14} and S_{94} are dominated by $N \rightarrow B$ charge transfer while local $N \rightarrow N$ and $B \rightarrow B$ contributions are also visible for S_{14} and S_{94} transitions. For MBNF-Al, the block denoted by $N \rightarrow B$ is the darkest for all three dominant transitions (S_{51} , S_{61} and S_{77}) indicating majority charge transfer from nitrogen to boron.

However, in addition, for S_{61} and S_{77} transitions, a charge transfer also occurs between $N \rightarrow H$. The Al-atom does not play an important role in any of the investigated transitions. In case of MBNF-Co, S_7 and S_9 transitions are primarily characterized by a local excitation on the cobalt atom. In addition, slight charge transfer also occurs between $B \rightarrow M$, $M \rightarrow B$ and $N \rightarrow M$. In S_{69} and S_{96} transitions, the most prominent charge transfer occurs between $N \rightarrow B$ (S_{69}) and $M \rightarrow B$ (S_{96}). For S_{96} , slight charge transfers also occur between $B \rightarrow B$, $N \rightarrow B$ and $M \rightarrow H$. Lastly, the MBNF-Cu is characterized by a mixed charge transfer. The S_1 transition is characterized by an even mixture between the $B \rightarrow M$ and $M \rightarrow B$ charge transfers as well as the corresponding local contributions ($M \rightarrow M$, $B \rightarrow B$). Further, the S_{17} transition consists of $B \rightarrow H$ and $M \rightarrow H$ transfer, followed by $N \rightarrow B$ and $N \rightarrow H$ for S_{55} transition and then the S_{84} transition which is entirely characterized by $N \rightarrow B$ charge transfer. Interesting observation from our previous report³¹ on metal doped GNRs suggested a dominant charge transfer from metal to rest-of-graphene. However, in this study, we observed not very significant charge transfer (in comparison with $N \rightarrow B$) from metal atom (upon absorption) for S_{96} , S_9 (in MBNF-Co), and S_1 , S_{17} (in MBNF-Cu) only. Also, local excitation within metal atom was also visible. Generally speaking, the charge transfer number analysis provides a consistent picture with the NTO analysis of **Fig. 3** but yields a somewhat more compact description.

Fig. 4 Electron-hole correlation plots (4X4 matrix) of dominant excitations ($S_0 \rightarrow S_n$). Color scale is from 0 (White) to 1 (Black). a) Pure, b) MBNF-Al, c) MBNF-Co, and d) MBNF-Cu. The four fragments are **M** (metal atom) (except in a)), **H** (hydrogens), **B** (borons) and **N** (nitrogens). The $N \rightarrow B$ etc. symbols on the top image represent the charge transfer between the respective fragments.

3.4 Electron-hole population analysis

It is now intended to analyze the nature of the singlet transitions described in **Table 1**, based on the electron-hole (e-h) population analysis, which was obtained by using the post processing tool TheoDORE. These populations are given according to

$$q_A^h = \sum_B \Omega_{AB}$$

for the hole population on fragment A and

$$q_B^e = \sum_A \Omega_{AB}$$

for the electron population on fragment B. Here, again, analysis was done for fragments according to the atom types.

Firstly, in pure BNF, the $S_0 \rightarrow S_2$ transition is of $\pi\pi^*$ type where the hole and electron are concentrated on the nitrogen atoms and boron atoms, respectively. It is well supported by the e-h population analysis with 93% hole character on nitrogen and 94% electron character on boron, indicating that it is an $N \rightarrow B$ excitation. Similarly, the $S_0 \rightarrow S_{14}$ transition is also of $\pi\pi^*$ nature (from $N \rightarrow B$) with 88% hole character on nitrogen and 88% electron character on boron. Lastly, the $S_0 \rightarrow S_{94}$ transition is of $\pi\pi^*$ character, with 77% hole character on nitrogen and 76% electron character on boron. But, here the orbitals are more delocalized as compared to the other transitions.

In case of MBNF-Al, the $S_0 \rightarrow S_{51}$ transition is of $\pi\pi^*$ type, with 63% hole character on nitrogen and 61% electron character on boron. Interestingly, the hole character of boron has increased from ~16% in pure form, to ~20% in MBNF-Al. The $S_0 \rightarrow S_{61}$ transition is a mixed transition,

with $\pi\pi^*$ character (64% hole character on nitrogen and 43% electron character on boron), 15% electron character on aluminium atom indicating a N->Al excitation and Rydberg character with 30% electron character on hydrogen atom. Lastly, the $S_0 \rightarrow S_{77}$ transition is of $\pi\pi^*$ and Rydberg nature both, with the 52% hole character on nitrogen, 44% electron character on boron and 37% electron character on hydrogen.

Furthermore, for MBNF-Co, the $S_0 \rightarrow S_7$ transition is a local excitation, with 70% hole and 65% electron character both on the cobalt atom itself. The same is valid for the $S_0 \rightarrow S_9$ transition, with 65% and 68% hole and electron character. However, the $S_0 \rightarrow S_{69}$ transition is of $\pi\pi^*$ type, with 71% hole on nitrogen and 53% electron on boron. The $S_0 \rightarrow S_{96}$ transition is an interesting one, where ~24% hole character is on boron and nitrogen both and 43% on cobalt atom, and 60% electron character on boron. This indicates that excitation could be from N->B ($\pi\pi^*$), N->H (Rydberg), Co->N or Co->B.

Lastly, for the MBNF-Cu, the $S_0 \rightarrow S_1$ excitation is a local excitation due to 37% hole character and 48% electron both on the copper atom, or, 48% hole character and 38% electron both on the boron. The $S_0 \rightarrow S_{17}$ excitation could be from Cu->H (Rydberg), B->B (local) or B->H (Rydberg), with hole (35%) on Copper, electron (70%) on hydrogen and 40% hole on boron. The $S_0 \rightarrow S_{55}$ excitation is a combination of $\pi\pi^*$ (N->B) and Rydberg state (N->H) with 55% hole on nitrogen, 41% electron on boron and 34% electron on hydrogen. The last dominant transition $S_0 \rightarrow S_{84}$ is purely of $\pi\pi^*$ character, with 65% hole character on nitrogen and 65% electron character on boron.

3.5 Exciton sizes

Root mean square electron-hole distances (d-eh) or exciton size determination is crucial in understanding the nature of excitons. Small exciton size indicates a tightly bound exciton, whereas large exciton size means a loosely bound exciton. It was noticed that a tightly bound exciton formed during absorption, leads to energy loss during the charge separation process³⁸. This is crucial in photovoltaic devices. Hence a larger exciton is preferred, which would result in the lower exciton binding energy^{39,40}. Exciton sizes (d-eh) are determined from the following equation, as described previously,²⁵ [S. A. Mewes, J.-M. Mewes, A. Dreuw, F. Plasser PCCP 2016, 18, 2548] and are derived from the TheoDORÉ package³³.

$$d\text{-eh} = \sqrt{\frac{1}{\Omega} \sum_{A,B} \Omega_{AB} r_{AB}^2}$$

where Ω_{AB} are the charge transfer numbers, and r_{AB} is the distance between the atoms **A** and **B**, and Ω the normalization factor is computed as the summation over all Ω_{AB} . As opposed to the previous analysis, the summation goes over individual atoms in this case. At this point it should be noted that the employed pointcharge approximation cannot be directly translated to exciton binding energies, as this would encounter a division by zero. Therefore, only exciton sizes are computed. **Table 2** shows the calculated values of the exciton sizes for the dominant singlet excitations.

Table 2. Exciton sizes (Å) corresponding to the dominant excitations for all the BNFs are listed.

BNF	Excited State (S_n)	Exciton size (Å)
Pure	S_2	5.68
	S_{14}	5.20
	S_{94}	5.01
MBNF-Al	S_{51}	4.70
	S_{61}	5.0
	S_{77}	5.52
MBNF-Co	S_7	2.35
	S_9	2.18
	S_{69}	5.48
	S_{96}	5.31
MBNF-Cu	S_1	2.82
	S_{17}	4.76
	S_{55}	5.75
	S_{84}	4.56

Materials with a large exciton radius are preferred in the photovoltaic application. In this study, the pure BNF would be the preferred candidate due to its large exciton sizes as compared to metal doped BNFs. The exciton sizes of all the BNFs for the dominant transitions range within 2.18-5.75Å. Exciton sizes have been directly related to the delocalization of electron density⁴¹, even though it should be noted that this interpretation changes for strongly correlated exciton states²⁶. In the present study, we have used the exciton size to study the extent of electron density delocalization. For the pure BNF, the S_{94} transition is the one with the least electron delocalization as compared to S_2 and S_{14} transitions. It is also well supported through NTO

analysis where the spread of exciton wavefunction is minimal from hole to electron NTO. In case of MBNF-Al, S_{77} transition has the largest exciton radius (5.52 Å) indicating the highest electron delocalization compared to the S_{51} and S_{61} transitions. This is well correlated with the NTO analysis where the spread of electron density is larger on absorption. Next, in MBNF-Co, S_7 is characterized by the lowest exciton radius of 2.35 Å. This is well explained by observing NTOs where the electron density is floating around the metal atom itself, upon absorption resulting in the least electron delocalization. On the contrary, the S_{96} transition is featured with the highest electron delocalization. Lastly, in MBNF-Cu, the S_1 transition is characterized by the least delocalization (exciton size= 2.82 Å) due to the minimal movement of the electron density from the metal atom. However, the S_{55} excitation demonstrates the highest delocalization on absorption, with the electron cloud spanning a larger area.

4. Conclusion

Electronic excitations upon absorption in boron nitride flakes (BNFs) both in pure ($B_{15}N_{15}H_{14}$) and neutral single-metal-atom doped ($B_{15}N_{14}H_{14}-X$, where $X= Al, Co, \text{ and } Cu$) forms were studied with the help of TDDFT calculations and transition density matrix based analysis. All the BNFs absorb in the UV range. However, strong red shifts were seen for all metal doped cases, with the strongest shift for MBNF-Co. Different analysis methods were applied to illustrate different aspects of the excitations. The natural transition orbital analysis was applied to illustrate the absorption process in the orbital picture and helped in understanding the electron delocalization upon absorption. Charge transfer plots were analyzed and it was found that in pure BNF, charge transfer is primarily from $N \rightarrow B$, however, a more diverse charge transfer occurs in metal doped forms, and in the case of MBNF-Cu and MBNF-Co strong involvement of the metal atom was found. Electron-hole population analysis was done to determine the nature of excitations ($\pi\pi^*$, Rydberg or local). Lastly, the exciton sizes were calculated and found to be in the range 2.18-5.75 Å for all the BNFs, and were used in the electron delocalization analysis. Generally, a consistent description was obtained between the various analysis methods. This study illustrates how strongly the excited state properties in BNF can vary upon doping and improves the understanding of electronic excitations in boron-nitride nanomaterials, which would be beneficial in photovoltaic applications. Furthermore, it serves as an exemplary investigation of how excited state analysis methods can be applied to maximize the insight gained from excited state computations performed in extended systems. In future, we further wish to study the effect of size and shape of BN flakes on the electronic and optical properties.

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